

# UTC UNISONIC TECHNOLOGIES CO., LTD

6N65K-TA **Preliminary** Power MOSFET

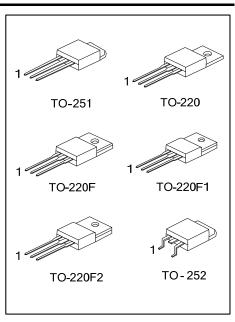
## **6.0A, 650V N-CHANNEL POWER MOSFET**

#### DESCRIPTION

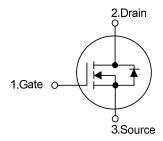
The UTC 6N65K-TA is a high voltage power MOSFET designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche characteristics. This power MOSFET is usually used in high speed switching applications of switching power supplies and adaptors.

#### **FEATURES**

- \*  $R_{DS(ON)}$  < 1.6 $\Omega$  @ $V_{GS}$  = 10V,  $I_{D}$  = 3A
- \* Fast switching capability
- \* Avalanche energy tested
- \* Improved dv/dt capability, high ruggedness



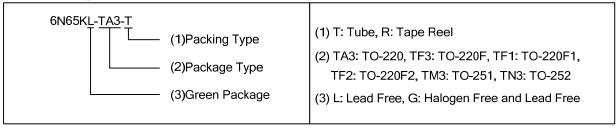
### **SYMBOL**



### **ORDERING INFORMATION**

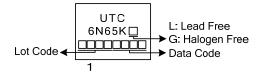
Ordering Number		Dookogo	Pin Assignment			Deakins	
Lead Free	Halogen Free	Package	1	2	3	Packing	
6N65KL-TA3-T	6N65KG-TA3-T	TO-220	G	D	S	Tube	
6N65KL-TF1-T	6N65KG-TF1-T	TO-220F1	G	D	S	Tube	
6N65KL-TF2-T	6N65KG-TF2-T	TO-220F2	G	D	S	Tube	
6N65KL-TF3-T	6N65KG-TF3-T	TO-220F	G	D	S	Tube	
6N65KL-TM3-R	6N65KG-TM3-R	TO-251	G	D	S	Tape Reel	
6N65KL-TN3-R	6N65KG-TN3-R	TO-252	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



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## **■** MARKING



## ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>C</sub> = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	650	V
Gate-Source Voltage		V <sub>GSS</sub>	±30	V
Avalanche Current (Note 2)		I <sub>AR</sub>	6	Α
Continuous Drain Current		$I_{D}$	6	Α
Pulsed Drain Current (Note 2)		$I_{DM}$	24	Α
Avalanche Energy	Single Pulsed (Note 3)	E <sub>AS</sub>	300	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	3.0	ns
	TO-220		125	W
Power Dissipation	TO-220F/TO-220F1	Б	40	W
	TO-220F2	$P_D$	42	W
	TO-251/TO-252		55	W
Junction Temperature		$T_J$	+150	°C
Operating Temperature		$T_OPR$	-55 ~ <b>+</b> 150	°C
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating : Pulse width limited by  $T_{\mathsf{J}}$
- 3. L = 17mH,  $I_{AS}$  = 6.0A,  $V_{DD}$  = 50V,  $R_G$  = 25  $\Omega$ , Starting  $T_J$  = 25°C
- 4.  $I_{SD} \le 6A$ , di/dt  $\le 200A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_J = 25^{\circ}C$

## **■ THERMAL DATA**

PARAMETER	PACKAGE	SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F TO-220F1/TO-220F2	θја	62.5	°C/W
	TO-251/TO-252		110	°C/W
Junction to Case	TO-220		1.0	°C/W
	TO-220F/TO-220F1	۵	3.125	°C/W
	TO-220F2	$\theta_{JC}$	2.97	°C/W
	TO-251/TO-252		2.27	°C/W

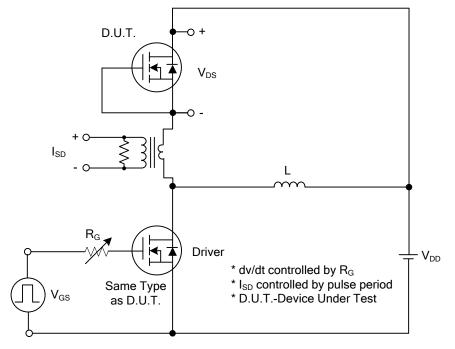
## ■ **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> =25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNI T
OFF CHARACTERISTICS				ı	ı		ı
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 250\mu A$	650			V
Drain-Source Leakage Current		I <sub>DSS</sub>	V <sub>DS</sub> = 650V, V <sub>GS</sub> = 0V			10	μΑ
Gate- Source Leakage Current	Forward	I <sub>GSS</sub>	V <sub>GS</sub> =+30V, V <sub>DS</sub> =0V			100	nA
	Reverse		V <sub>GS</sub> =-30V, V <sub>DS</sub> =0V			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS}/\triangle T_{J}$	I <sub>D</sub> =250μA, Referenced to 25°C		0.53		V/°C
ON CHARACTERISTICS							
Gate Threshold Voltage		V <sub>GS(TH)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance		R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 3A			1.6	Ω
DYNAMIC CHARACTERISTICS			•				
Input Capacitance	nput Capacitance				835		pF
Output Capacitance		C <sub>ISS</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0 MHz		76		pF
Reverse Transfer Capacitance		C <sub>RSS</sub>			6		pF
SWITCHING CHARACTERISTICS	3		•				
Total Gate Charge		$Q_{G}$	\\ _50\\ \\ _40\\   _40\		62		nC
Gate-Source Charge		$Q_GS$	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.3A,		5.6		nC
Gate-Drain Charge		$Q_GD$	-I <sub>G</sub> =100μA (Note 1, 2)		6		nC
Turn-On Delay Time		t <sub>D(ON)</sub>			40		ns
Turn-On Rise Time		t <sub>R</sub>	$V_{DD}$ =30V, $V_{GS}$ =10V, $I_{D}$ =0.5A,		34		ns
Turn-Off Delay Time		t <sub>D(OFF)</sub>	$R_G = 25\Omega$ (Note 1, 2)		155		ns
Turn-Off Fall Time		$t_{F}$			41		ns
DRAIN-SOURCE DIODE CHARA	CTERISTIC	S AND MAXII	MUM RATINGS	_	_	_	_
Maximum Continuous Drain-Source	e Diode					6	Α
Forward Current		I <sub>S</sub>				0	А
Maximum Pulsed Drain-Source Diode Forward Current		I <sub>SM</sub>				24	Α
						24	A
Drain-Source Diode Forward Voltage		$V_{SD}$	V <sub>GS</sub> =0V, I <sub>S</sub> =6.0A			1.4	V
Reverse Recovery Time		t <sub>RR</sub>	  -  V <sub>GS</sub> =0V, I <sub>S</sub> =6.0A,di/dt=100A/µs		430		ns
Reverse Recovery Charge		$Q_{RR}$	ν 65-0 ν , 15-0.0Α,αι/αι-100Α/μ5		3.0		μC

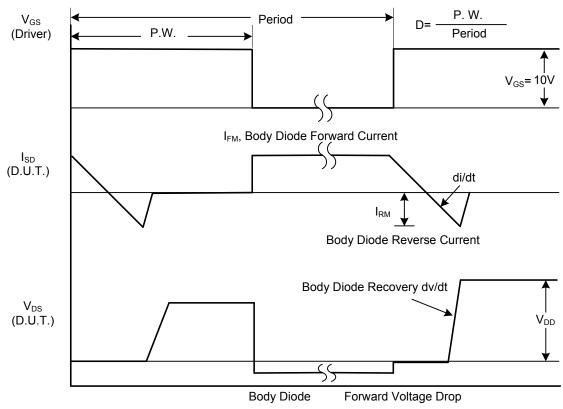
Notes: 1. Pulse Test: Pulse width  $\leq$  300 $\mu$ s, Duty cycle  $\leq$  2%.

<sup>2.</sup> Essentially independent of operating temperature.

## ■ TEST CIRCUITS AND WAVEFORMS

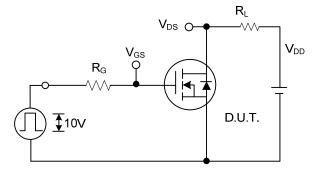


Peak Diode Recovery dv/dt Test Circuit

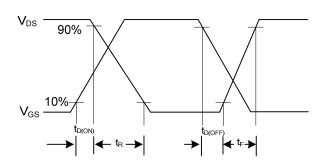


Peak Diode Recovery dv/dt Waveforms

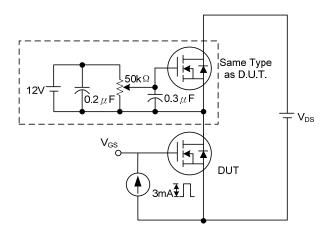
## ■ TEST CIRCUITS AND WAVEFORMS (Cont.)



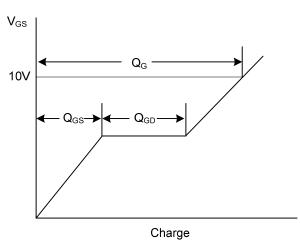
**Switching Test Circuit** 



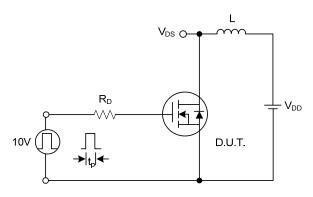
**Switching Waveforms** 



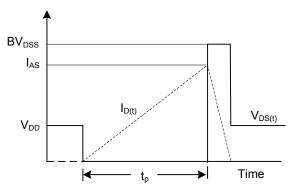
**Gate Charge Test Circuit** 



**Gate Charge Waveform** 



**Unclamped Inductive Switching Test Circuit** 



**Unclamped Inductive Switching Waveforms** 

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